Attorney Docket: 29936/39482 Inventors: Noh Yeal Kwak, et al. Title: METHOD OF FORMING AN ISOLATION FILM IN A SEMICONDUCTOR DEVICE Sheet 1 of 4 180 160 Thickness (A) 140 120 100 80 30KeV 20**K**eV 140 Thickness (A) 120 100 80 60 20KeV 30KeV 140 120 Thickness (A) 100 80 60 40 3E15 2E15 180 160 Thickness (A 140 120 100 2E15 3E15

FIG. 1A

FIG. 1B

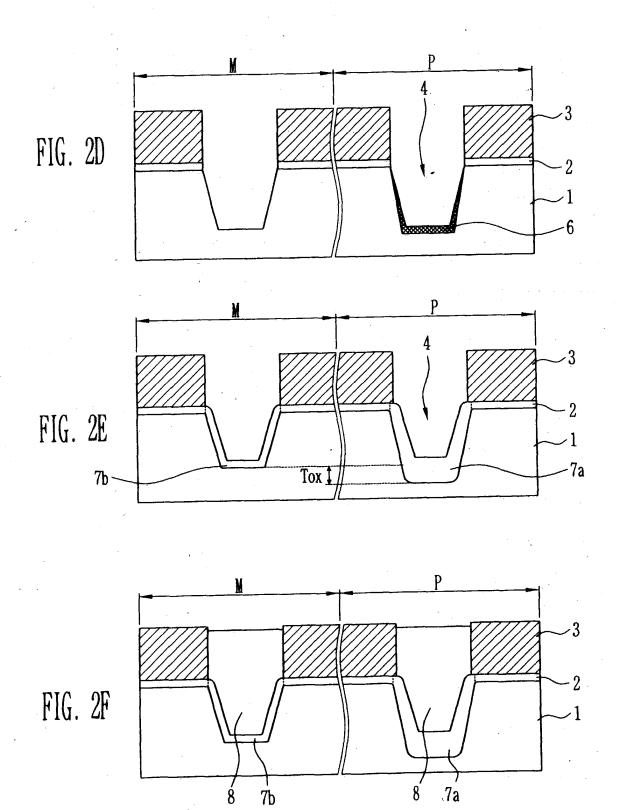
FIG. 1C

FIG. 1D

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FIG. 2A FIG. 2B Inert Ion FIG. 2C

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FIG. 3

